## **Darlington**

## 2SB1259



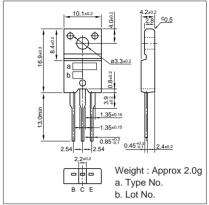
Silicon PNP Epitaxial Planar Transistor (Complement to type 2SD2081)

Application: Driver for Solenoid, Relay and Motor and General Purpose

Absolute maximum ratings (Ta=25°C)							
Symbol	2SB1259	Unit					
Vсво	-120	V					
VCEO	-120	V					
VEBO	-6	V					
Ic	-10(Pulse-15)	А					
lв	-1	А					
Pc	30(Tc=25°C)	W					
Tj	150	°C					
Tstg	-55 to +150	°C					

Electrical C	haracteristics	(Ta=25°C)		
Symbol	Conditions	2SB1259	Unit	
Ісво	Vcb=-120V	-10max	μΑ	
IEBO	VEB=-6V	-10max	mA	
V(BR)CEO	Ic=-10mA	-120min	V	
hfe	Vce=-4V, Ic=-5A	2000min		
Vce(sat)	Ic=-5A, IB=-10mA	-1.5max	V	
VBE(sat)	Ic=-5A, IB=-10mA	-2.0max	V	
fT	Vce=-12V, Ie=0.2A	100typ	MHz	
Сов	VcB=-10V, f=1MHz	145typ	pF	

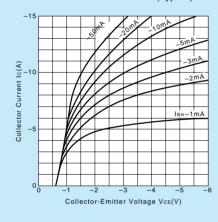
## External Dimensions FM20(TO220F)



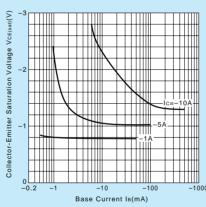
## ■Typical Switching Characteristics (Common Emitter)

Vcc	R <sub>L</sub>	Ic	V <sub>BB1</sub> (V)	VBB2	I <sub>B1</sub>	I <sub>B2</sub>	ton	tstg	tf
(V)	(Ω)	(A)		(V)	(mA)	(mA)	(µs)	(µs)	(µs)
-30	10	-3	-10	5	-6	6	0.6typ	1.6typ	0.5typ

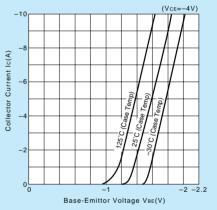




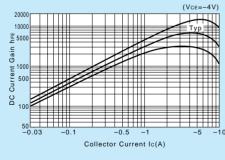
VcE(sat)-IB Characteristics (Typical)



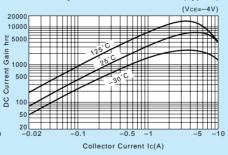
Ic-VBE Temperature Characteristics (Typical)



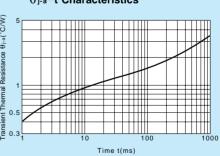
hFE-Ic Characteristics (Typical)



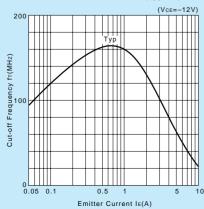
hfe-Ic Temperature Characteristics (Typical)



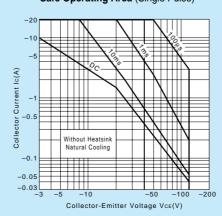
θ<sub>j-a</sub>-t Characteristics



fT-IE Characteristics (Typical)



Safe Operating Area (Single Pulse)



Pc-Ta Derating

